



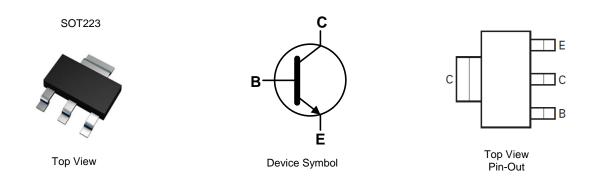
25V NPN MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > 25V
- I_C = 5A high Continuous Collector Current
- I_{CM} = 20A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 70mV @ 1A
- $R_{CE(sat)} = 50m\Omega$ for a low equivalent On-Resistance
- h_{FE} specified up to 20A for a high gain hold up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT1049ATA	AEC-Q101	FZT1049A	7	12	1,000
FZT1049ATC	AEC-Q101	FZT1049A	13	12	4,000

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

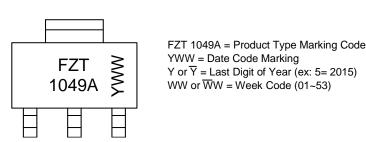
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information

Notes:

SOT223





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	5	А
Peak Pulse Current	I _{CM}	20	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		3.0	
Dewer Dissinction	(Note 6)	D D	2.0	w
Power Dissipation	(Note 7)	PD	1.6	vv
	(Note 8)		1.2	
	(Note 5)		41.7	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	62.5	
memai Resistance, Junction to Ambient	(Note 7)		78.1	°C/W
	(Note 8)		104	
Thermal Resistance Junction to Lead	(Note 9)	R _{0JL}	10.9	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under Notes: still air conditions whilst operating in a steady-state.

6. Same as note (5), except the device is mounted on 25mm x 25mm 2oz copper.

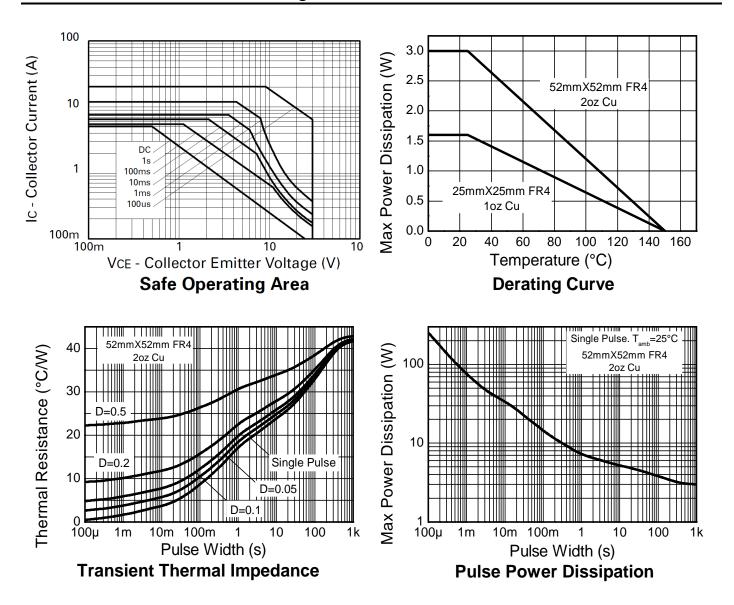
Same as note (5), except the device is mounted on 25mm 122 copper.
Same as note (5), except the device is mounted on 25mm 102 copper.
Same as note (5), except the device is mounted on minimum recommended pad layout.

9. Thermal resistance from junction to solder-point (at the end of the collector lead).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Observatoriatio	0	Min	T		1114	To at Oam dition
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	80	130	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CER}	80	130	-	V	$I_{\rm C} = 100 \mu {\rm A}$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	25	30	-	V	$I_{C} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BVEBO	7	9	-	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	-	0.3	10	nA	$V_{CB} = 35V$
Emitter Cutoff Current	I _{EBO}	-	0.3	10	nA	$V_{EB} = 4V$
		280	440	-		$I_{C} = 10 \text{mA}, V_{CE} = 2 \text{V}$
		300	450	-		$I_{C} = 0.5A, V_{CE} = 2V$
DC Current Transfer Static Ratio (Note 11)	h _{FE}	300	450	1,200		$I_{C} = 1A, V_{CE} = 2V$
		180	280	-		$I_{C} = -5A, V_{CE} = 2V$
		40	80	-		$I_{C} = 20A, V_{CE} = 2V$
	V _{CE(sat)}	-	35	60	mV	$I_{C} = 0.5A, I_{B} = 10mA$
Collector-Emitter Saturation Voltage (Note 11)		-	70	100		$I_{\rm C} = 1$ A, $I_{\rm B} = 10$ mA
Collector-Enlitter Saturation Voltage (Note 11)		-	180	250		$I_{C} = 3A, I_{B} = 30mA$
		-	250	330		$I_{\rm C} = 5A, I_{\rm B} = 50 {\rm mA}$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	-	950	1,050	mV	$I_{C} = 5A, I_{B} = 50mA$
Base-Emitter Turn-on Voltage (Note 11)	V _{BE(on)}	-	900	1,000	mV	$I_{C} = 5A, V_{CE} = 2V$
Transitional Frequency (Note 11)	f _T	-	180	-	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V},$ f = 100MHz
Output Capacitance	C _{obo}	-	45	60	pF	$V_{CB} = 10V$, f = 1MHz
Switching Time	ton	-	125	-	ns	$V_{CC} = 10V, I_C = 4A,$
	t _{OFF}	-	380	-	115	$I_{B1} = -I_{B2} = 40 \text{mA}$

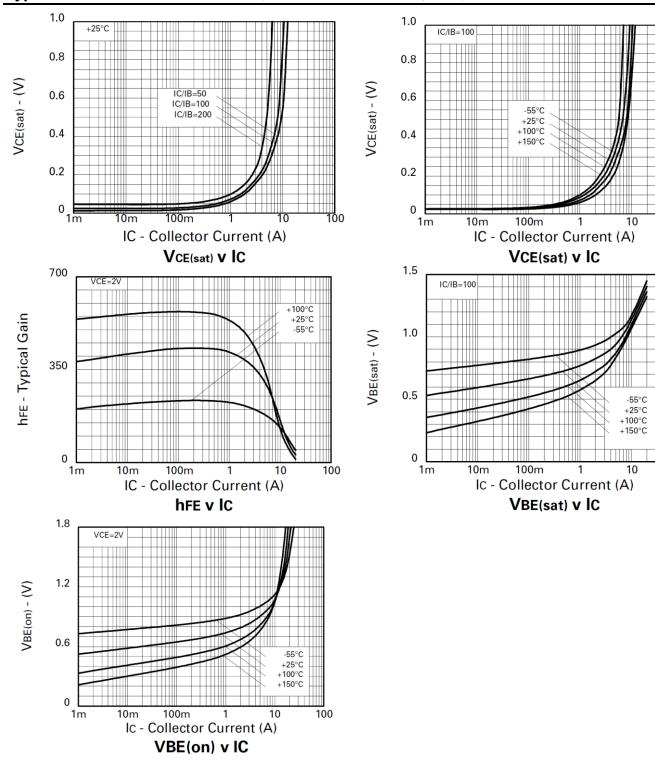
Note: 11. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



100

100

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

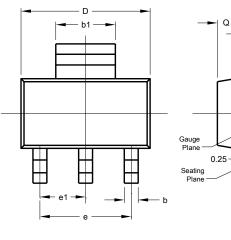
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

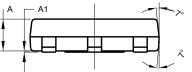
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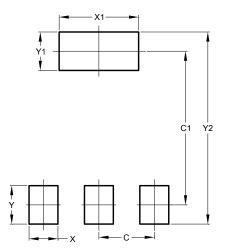




SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b1	2.90	3.10	3.00	
b2	0.60	0.80	0.70	
С	0.20	0.30	0.25	
D	6.45	6.55	6.50	
Е	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е			4.60	
e1	_	_	2.30	
L	0.85	1.05	0.95	
Q	0.84	0.94	0.89	
All [All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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